

HFA35HB60

PD-20379E

Ultrafast, Soft Recovery Diode Thru-Hole (TO-254AA) 600V, 22A

Features

- Single diode configuration
- Reduced RFI and EMI
- · Reduced snubbing
- Extensive characterization of recovery parameters
- Hermetic package
- Ceramic eyelets

Product Summary

V_R: 600V

• **V**_F: 1.75V

Q_{rr}: 575nC

di_{(rec)M}/dt: 270A/μs

Potential Applications

- DC-DC converter
- Motor drives

Product Validation

Qualified according to MIL-PRF-19500 for space applications



Description

HFA35HB60 is part of the International Rectifier HiRel family of products. These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The soft-ness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motor drives and other applications where switching losses are significant portion of the total losses.

Ordering Information

Table 1 Ordering options

Part number	Package	Screening Level			
HFA35HB60	TO-254AA	сотѕ			
HFA35HB60SCV	TO-254AA	JANTXV-equivalent			
HFA35HB60SCX	TO-254AA	JANTX-equivalent			
HFA35HB60SCS	TO-254AA	S-level			

HFA35HB60

FRED Ultrafast, Soft Recovery Diode



Table of contents

Table of contents

Feat	tures	1
Pote	ential Applications	1
	duct Validation	
	cription	
	lering Information	
	ole of contents	
1		
- 2	Device Characteristics	
2.1		
2.2	Dynamic Recovery Characteristics	
2.3	Thermal-Mechanical Characteristics	4
3	Electrical Characteristics Curves	5
4	Test Circuit	8
5	Package Outline	
_	rision history	

FRED Ultrafast, Soft Recovery Diode



Absolute Maximum Ratings

1 Absolute Maximum Ratings

Table 2 Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_R	DC Reverse Voltage	600	V
l _F	Continuous Forward Current, T _C =100 °C ¹	22	Α
I _{FSM}	Single pulse Forward Current, T _c = 25°C ²	225	Α
$P_D @ T_C = 25^{\circ}C$	Maximum Power Dissipation	83	W
T _J T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
Wt	Weight	9.3 (Typical)	g

3 of 11

2022-06-02

¹ DC = 50% rect. wave

 $^{^2}$ ½ sine wave, 60 Hz, Pulse width = 8.33 ms



Device Characteristics

2 Device Characteristics

2.1 Electrical Characteristics

Table 3 Electrical Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
V_{BR}	Cathode Anode Breakdown Voltage	600	_	_	V	$I_R = 100 \mu A$
		_	_	1.55		$I_F = 22A, T_J = -55^{\circ}C$
	Forward Voltage Drop See Fig. 1	_	_	1.75		I _F = 22A, T _J = 25°C
V_{F}		_	_	2.25	\ \	I _F = 45A, T _J = 25°C
		_	_	1.64		I _F = 22A, T _J = 125°C
I _R	Reverse Leakage Current	_	_	10	μΑ	$V_R = V_R$ Rated
	See Fig. 2	_	_	1.0	mA	V _R = 480V, T _J = 125°C
Ст	Junction Capacitance See Fig. 3	_	56	59	pF	V _R = 200V
Ls	Series Inductance	_	8.7	_	nH	Measured from center of bond pad to end of anode bonding wire

2.2 Dynamic Recovery Characteristics

Table 4 Dynamic Recovery Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Condition	s
t _{rr1}	Reverse Recovery Time	_	60	97		T _J = 25°C	
t _{rr2}	See Fig. 5	-	110	_	ns	T _J = 125°C	I _F = 22A
I _{RRM1}	Peak Recovery Current	_	5.2	_		T _J = 25°C	
I _{RRM2}	See Fig. 6	-	8.5	_	A	T _J = 125°C	V _R = 200V
Q _{rr1}	Reverse Recovery Charge	_	190	575		T _J = 25°C	
Q _{rr2}	See Fig. 7	_	560	_	nC	T _J = 125°C	$d_{if}/dt = 200 A/ \mu s$
$di_{(rec)M}/dt_1$	Peak Rate of Fall of Recovery	_	270	_		T _J = 25°C	
di _{(rec)M} /dt ₂	Current During t₀ See Fig. 8	_	170	_	A/ μs	T _J = 125°C	

2.3 Thermal-Mechanical Characteristics

Table 5 Thermal-Mechanical Characteristics

Symbol	Parameter		Max.	Unit
$R_{ heta JC}$	Junction to Case, Single Leg Conducting	1	1.5	°C/W

ICR HIRE

Electrical Characteristics Curves

3 Electrical Characteristics Curves

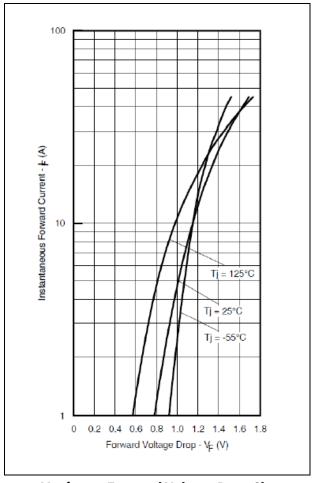


Figure 1 Maximum Forward Voltage Drop Characteristics

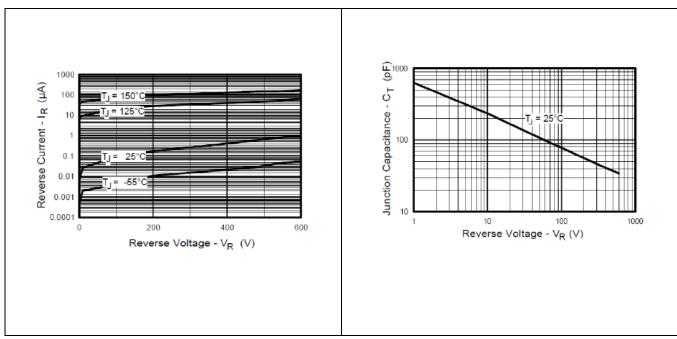


Figure 2 Typical Values of Reverse Current Vs. Reverse Voltage

Figure 3

Typical Junction Capacitance Vs. Reverse Voltage



Electrical Characteristics Curves

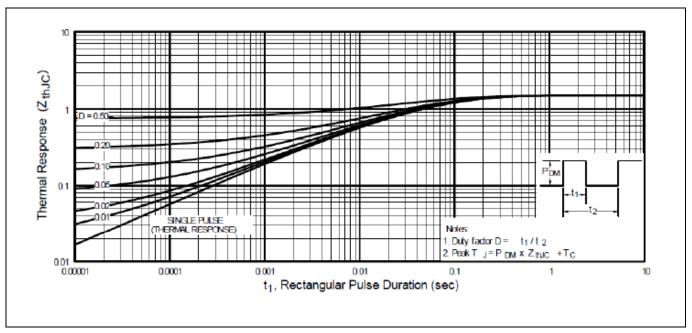


Figure 4 Maximum Thermal Impedance Z_{thJC} Characteristics

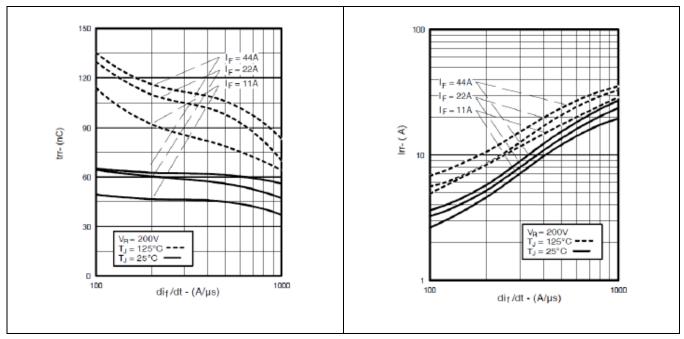


Figure 5 Typical Reverse Recovery Vs. d_{if}/dt Figure 6 Typical Recovery Current Vs. d_{if}/dt



Electrical Characteristics Curves

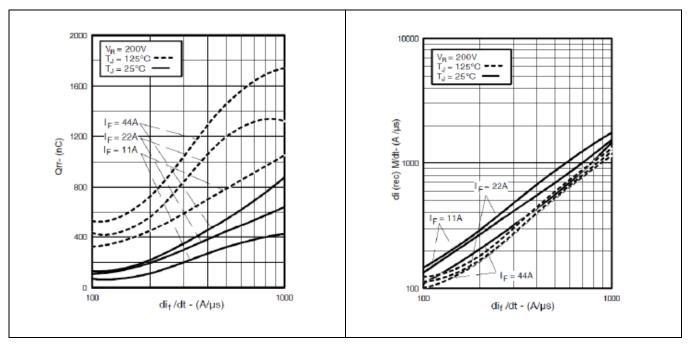


Figure 7 Typical Stored Charge Vs. d_{if}/dt

Figure 8 Typical di_{(rec)M}/dt Vs. d_{if}/dt



Test Circuit

4 Test Circuit

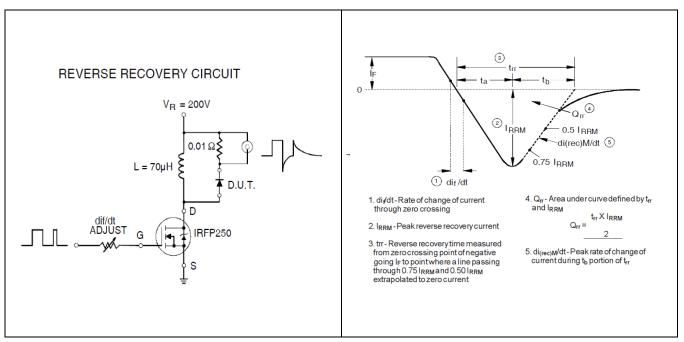


Figure 9 Reverse Recovery Parameter Test Circuit

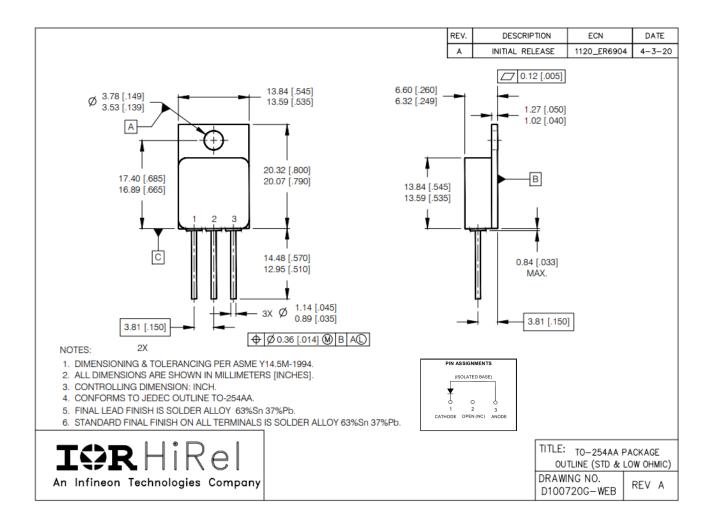
Figure 10 Reverse Recovery Waveform and Definitions



Package Outline

5 Package Outline

Note: For the most updated package outline, please see the website: TO-254AA



HFA35HB60

FRED Ultrafast, Soft Recovery Diode



Revision history

Revision history

Document version	Date of release	Description of changes
	12/24/2010	Final datasheet (PD-20379)
Rev A	03/07/2013	Updated per ECN-1120-00911
Rev B	09/23/2016	Updated per ECN-1120-04743
Rev C	03/02/2018	Updated per ECN-1120-06010
Rev D	05/03/2021	Updated per ECN-1120-08526
Rev E	06/02/2022	Updated per ECN-1120-08972

Trademarks

All referenced product or service names and trademarks are the property of their respective owners.

Edition 2022-06-02

Published by

International Rectifier HiRel Products, Inc.

An Infineon Technologies company El Segundo, California 90245 USA

© 2022 Infineon Technologies AG. All Rights Reserved.

Do you have a question about this document?

Email: erratum@infineon.com

Document reference

IMPORTANT NOTICE

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

For further information on the product, technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies office (www.infineon.com).

WARNINGS

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest International Rectifier HiRel Products, Inc., an Infineon Technologies company, office.

International Rectifier HiRel Components may only be used in life-support devices or systems with the expressed written approval of International Rectifier HiRel Products, Inc., an Infineon Technologies company, if failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety and effectiveness of that device or system.

Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.

Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.